Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	11	pad\$1 same plug\$1 same capacitor\$1 same MIM	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:32
L2	21	cylindrical same shape same pad\$1 same capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:38
L3	1552562	platinum or Pt	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:39
L4	80158	barrier adj layer\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:39
L5	567609	capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:39
L6	627436	capacitor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:39
L7	40760	plug\$1 and pad\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:40
L8	266	3 and 4 and 5 and 6 and 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:40
L9	0	8 and seiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:41

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L10	. 253	8 and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:41
L11	210	10 and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:43
L12	0	Ptatinum adj barrier adj layer\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:44
L13	2019	Platinum with barrier with layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:44
L14	43	11 and 13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:49
L15	13	Ru adj barrier adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 12:58
L16	2	"20040262661"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 14:15
L17	4935	metal adj insulator adj metal\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 14:16
L18	627436	capacitor\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 14:16
L19	2660	17 and 18	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 14:17

L20	295	19 and via\$1 and pad\$1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/23 14:17
L21	255	20 and ( semiconductor memory )	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR _	OFF	2005/06/23 14:18